

G4S06515HT

650V/ 15A Silicon Carbide Power Schottky Barrier Diode

Features

- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

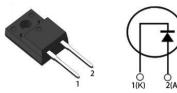
Key Characteristics			
V _{RRM}	650	V	
I _{F,} T _c ≤106°C	15	Α	
Qc	31	nC	

Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements

Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV









Part No.	Package Type	Marking
G4S06515HT	TO-220F	G4S06515HT

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit	
Repetitive Peak Reverse Voltage	V_{RRM}		650	V	
Surge Peak Reverse Voltage	V_{RSM}		650	V	
DC Blocking Voltage	V_{DC}		650	V	
Continuous Forward Current	I _F	T _C =25°C T _C =106°C T _C =125°C	23.8 15 12.5	А	
Repetitive Peak Forward Surge Current	I _{FRM}	$T_C=25^{\circ}\mathrm{C}$, tp=10ms , Half Sine Wave, D=0.3	50	А	
Non-repetitive Peak Forward Surge Current	I _{FSM}	T_{C} =25°C, tp=10ms , Half Sine Wave	130	А	
Power Dissipation	P _{TOT}	$T_C=25^{\circ}C$ $T_C=110^{\circ}C$	63 27	W	
Operating Junction	Tj		-55°C to 175°C	°C	
Storage Temperature	T_{stg}		-55°C to 175°C	°C	
Mounting Torque		M3 Screw 6-32 Screw	1 8.8	Nm lbf-in	

Thermal Characteristics

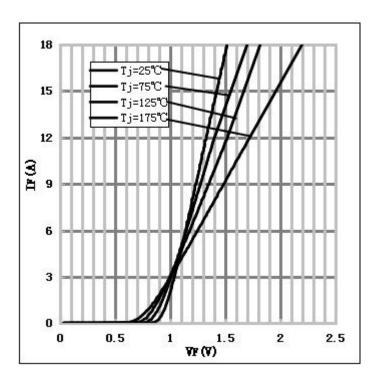
Daramatar	Symbol Test Condition	Toot Condition Value	Tast Condition Value	Unit
Parameter		Тур.	Unit	
Thermal resistance from junction to case	R _{th JC}		2.38	°C/W

Electrical Characteristics

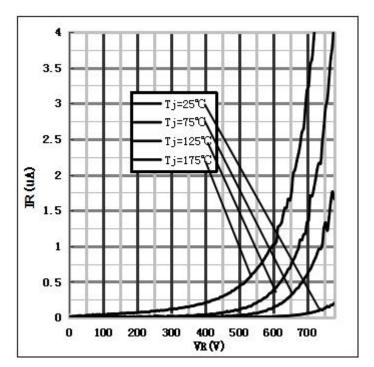
Donomotor	Course had	Took Conditions	Numerical		l lasit	
Parameter	Symbol	Test Conditions	Тур.	Max.	Unit	
Famurand Valtage	V _F	I _F =15A, T _j =25℃	1.5	1.7	.,	
Forward Voltage		I _F =15A, T _j =175℃	2	2.5	V	
Daviese Comment	I _R	V _R =650V, T _j =25℃	0.5	50		
Reverse Current		V _R =650V, T _j =175℃	1.4	100	μΑ	
		$V_R=400V, T_j=150^{\circ}C$				
Total Capacitive Charge	Q_{C}	$Qc = \int_0^{VR} C(V)dV$	31	-	nC	
	_	V_R =0V, T_j =25 $^{\circ}$ C, f=1MHZ	645	680		
Total Capacitance	C	V_R =200V, T_j =25 $^{\circ}$ C, f=1MHZ	58	61	pF	
		V_R =400V, T_j =25 $^{\circ}$ C , f=1MHZ	56	58		

Performance Graphs

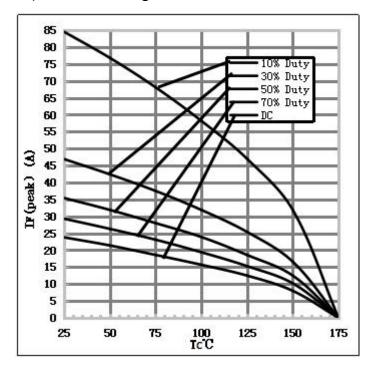
1) Forward IV characteristics as a function of Tj:



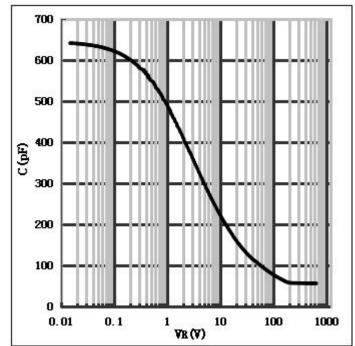
2) Reverse IV characteristics as a function of Tj:



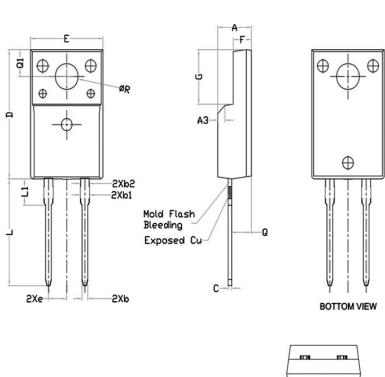
3) Current Derating:



4) Capacitance vs. reverse voltage:



Package TO-220F



Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash And Burrs Mold Flash Should Be Less Than 6 Mil.

Min.	Nom.	Max.	
4.60	4.70	4.80	
0.70	0.80	0.91	
1.20	1.30	1.47	
1.10	1.20	1.30	
0.45	0.50	0.63	
15.80	15.87	15.97	
2.54			
10.00	10.10	10.30	
2.44	2.54	2.64	
6.50	6.70	6.90	
12.90	13.10	13.30	
3.13	3.23	3.33	
2.65	2.75	2.85	
	4.60 0.70 1.20 1.10 0.45 15.80 10.00 2.44 6.50 12.90 3.13	4.60 4.70 0.70 0.80 1.20 1.30 1.10 1.20 0.45 0.50 15.80 15.87 2.54 10.00 10.10 2.44 2.54 6.50 6.70 12.90 13.10 3.13 3.23	

单位:mm

DIMENSIONS

3.20

3.08

3.30

3.18

3.40

3.28

Q1

ΦR

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: http://globalpowertech.cn/English/index.asp

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